

Refine Search

Search Results -

Terms	Documents
L13 and "semiconductor substrate"	11

Database:

US Pre-Grant Publication Full-Text Database
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Search:

L14  

Search History

DATE: Wednesday, November 30, 2005 [Printable Copy](#) [Create Case](#)

Set Name Query

side by side

Hit Count Set Name

result set

DB=PGPB; PLUR=YES; OP=OR

<u>L14</u>	L13 and "semiconductor substrate"	11	<u>L14</u>
<u>L13</u>	L12 and (passivation or insulation or insulating or dielectric)	68	<u>L13</u>
<u>L12</u>	inductor and core and liner	102	<u>L12</u>

DB=USPT; PLUR=YES; OP=OR

<u>L11</u>	L8 and "substrate"	36	<u>L11</u>
<u>L10</u>	L8 and "semiconductor substrate"	9	<u>L10</u>
<u>L9</u>	L8 and "semiconductor substrate"	89603	<u>L9</u>
<u>L8</u>	L7 and (passivation or insulation or insulating or dielectric)	100	<u>L8</u>
<u>L7</u>	inductor and core and liner	138	<u>L7</u>
<u>L6</u>	6376914	9	<u>L6</u>

DB=PGPB; PLUR=YES; OP=OR

<u>L5</u>	L4 and core and liner	1	<u>L5</u>
<u>L4</u>	20050167780	1	<u>L4</u>
<u>L3</u>	L2	0	<u>L3</u>

DB=USPT; PLUR=YES; OP=OR

L2 20050167780

0 L2

L1 5793272

59 L1

END OF SEARCH HISTORY

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